



DMP6018LPSQ

60V P-CHANNEL ENHANCEMENT MODE MOSFET

PowerDI5060-8

Product Summary

BV _{DSS}	Rds(on)	I⊳ Тс = +25°С
-60V	18mΩ @ V _{GS} = -10V	-60A
-007	26mΩ @ V _{GS} = -4.5V	-50A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- DC-DC Converters
- Load Switch

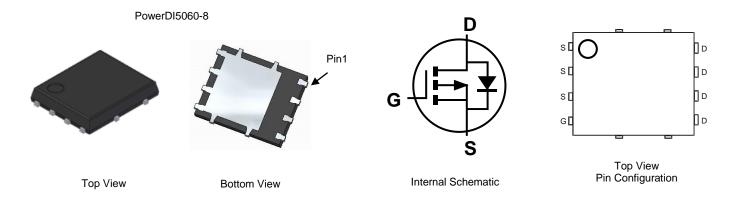
Features and Benefits

- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low RDS(ON) Minimizes On State Losses
- Low Input Capacitance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMP6018LPSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: PowerDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.097 grams (Approximate)



Ordering Information (Note 4)

Notes:

Case	Packaging
PowerDI5060-8	2,500 / Tape & Reel

EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

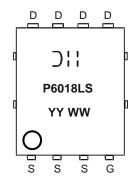
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

PowerDI is a registered trademark of Diodes Incorporated.



Marking Information



) || = Manufacturer's Marking P6018LS = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 21 = 2021) WW = Week (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			Vdss	-60	V
Gate-Source Voltage			Vgss	±20	V
Continuous Drain Current, $V_{GS} = -10V$ (Note 6)	Steady State	T _C = +25°C T _C = +70°C	D	-60 -48	А
Maximum Continuous Body Diode Forward Current			ls	-60	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			Ідм	-240	A
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)			lsм	-240	A
Avalanche Current, L = 0.3mH			las	-47	A
Avalanche Energy, L = 0.3mH			Eas	331	mJ

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	2.6	W
Thermal Resistance, Junction to Ambient (Note 5)		Reja	50	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	113	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	1.1	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate. 6. Thermal resistance from junction to soldering point (on the exposed drain pad).

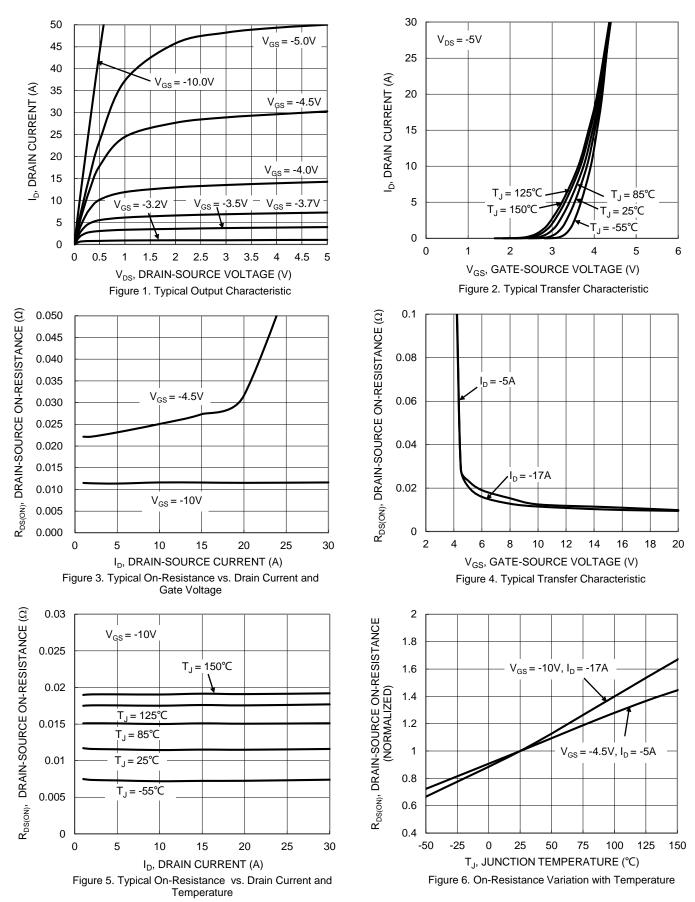


Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

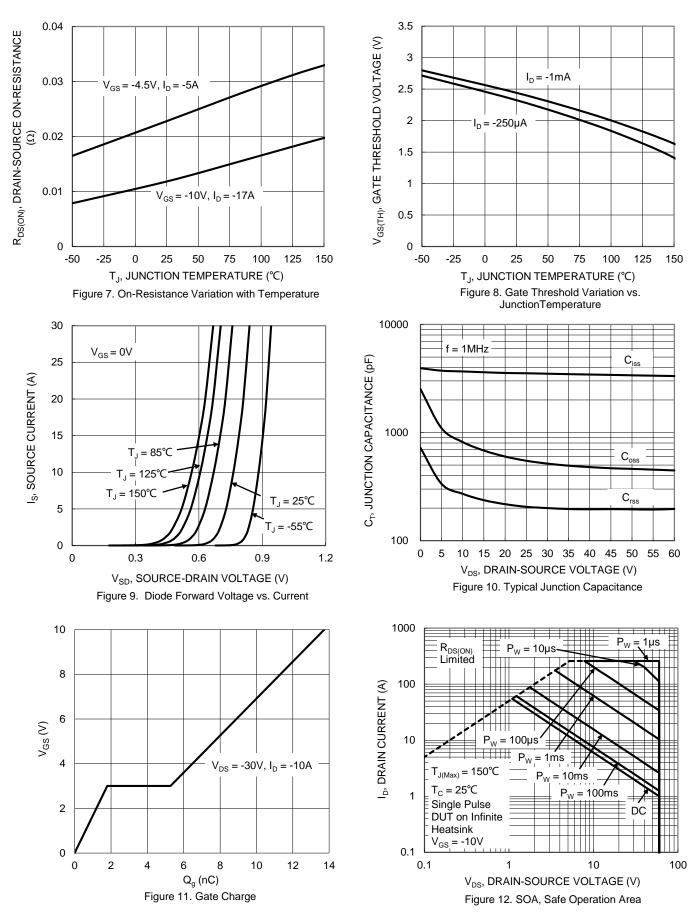
			-			T (0)	
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)			r	r			
Drain-Source Breakdown Voltage	BVDSS	-60	—	—	V	Vgs = 0V, Ip = -250µA	
Zero Gate Voltage Drain Current	IDSS	_	—	-1	μA	$V_{DS} = -60V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	—	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	-1.5	—	-2.5	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	
Static Drain-Source On-Resistance	Deserve	_	13	18	mΩ	Vgs = -10V, ID = -17A	
Static Drain-Source On-Resistance	Rds(on)	_	22	26	11122	VGS = -4.5V, ID = -5A	
Diode Forward Voltage	V _{SD}		-0.76	-1.0	V	V _{GS} = 0V, I _S = -17A	
DYNAMIC CHARACTERISTICS (Note 8)						·	
Input Capacitance	Ciss	_	3505	—		$V_{DS} = -30V, V_{GS} = 0V,$ f = 1MHz	
Output Capacitance	Coss	_	516	_	pF		
Reverse Transfer Capacitance	Crss	_	200	_			
Gate Resistance	Rg	_	9.1	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = -4.5V)	Qg	_	7.1	_		V _{DS} = -30V, I _D = -10A	
Total Gate Charge (V _{GS} = -10V)	Qg	_	13.7	_			
Gate-Source Charge	Q _{gs}	_	1.8	_	nC		
Gate-Drain Charge	Qgd	_	3.5	_			
Turn-On Delay Time	t _{D(ON)}		3.9	_		$V_{DD} = -30V, V_{GS} = -10V,$ $I_D = -10A, R_G = 2.5\Omega$	
Turn-On Rise Time	tR	_	6.7	_			
Turn-Off Delay Time	tD(OFF)		16.0	_	ns		
Turn-Off Fall Time	tr		7.2	_	1		
Body Diode Reverse Recovery Time	t _{RR}		32	_	ns		
Body Diode Reverse Recovery Charge	Qrr	_	28	_	nC	Is = -17Α, di/dt = 100Α/μs	

Notes:7. Short duration pulse test used to minimize self-heating effect.8. Guaranteed by design. Not subject to product testing.



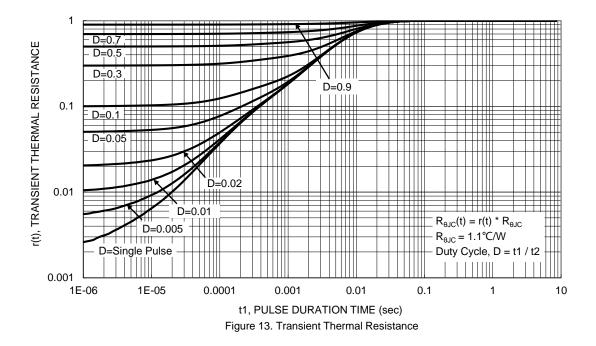






DMP6018LPSQ Document number: DS42662 Rev. 4 - 2



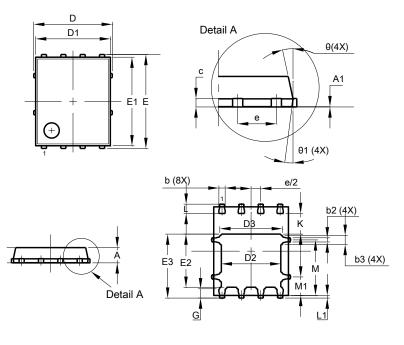




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

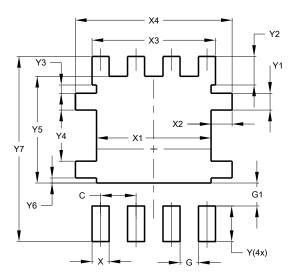


PowerDI5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D		5.15 BSC	;		
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	3.90 4.30 4.			
E	6.15 BSC				
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е	1.27 BSC				
G	0.51	0.71	0.61		
ĸ	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
Al	All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610



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